

Agilent E8247C/57C PSG CW and Analog Signal Generators

Data Sheet



All specifications and characteristics apply over a 0 to 55°C range (unless otherwise stated) and apply after a 45 minute warm-up time. Supplemental characteristics, denoted as typical or nominal, provide additional (non-warranted) information.

PSG Signal Generators

	Option 520	Option 540
	250 kHz to 20 GHz	250 kHz to 40 GHz
CW only	E8247C	E8247C
Analog	E8257C	E8257C
Vector	E8267C	

(See E8267C data sheet for PSG Vector Signal Generator specifications)

Definitions

Specifications (spec): represent warranted performance.

Typical (typ): performance is not warranted. It applies at 25°C. 80% of all products meet typical performance.

Nominal (nom): values are not warranted. They represent the value of a parameter that is most likely to occur; the expected or mean value. They are included to facilitate the application of the product.

Standard (std): No options are included when referring to the signal generator unless noted otherwise.



E8247C & E8257C PSG Signal Generators

Choose your required frequency range as an option when configuring your PSG series. Please refer to the related literature section for additional information.

Agilent microwave PSG CW/analog signal generators options

Frequency range	(required option)
Option 520	250 kHz to 20 GHz
Option 540	250 kHz to 40 GHz
Step attenuator	
Option 1E1	Adds output step attenuator
High output power	
Option 1EA	High RF output power
Enhanced phase noise	
Option UNR	Enhanced phase noise performance
Narrow pulse modulation	
Option 1E6	Provides narrow pulse modulation below 3.2GHz
Analog (ramp) sweep	
Option 007	Provides analog (ramp) sweep and scalar network analyzer interface
Connectors	
Option 1ED	Type-N (f) connector
Option 1EM	Moves all connector to rear panel

Specifications

Frequency

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$\begin{array}{c c c c c c c } \hline after 45 \ days & after 30 \ days \\ \hline emperature effects (typical) & < \pm 5 \times 10^{-9} \ 0 \ to \ 55^{\circ} \ C & < \pm 4.5 \times 10^{-9} \ 0 \ to \ 55^{\circ} \ C \\ \hline ine \ voltage effects (typical) & < \pm 2 \times 10^{-9} \ for & < \pm 2 \times 10^{-10} \ for \\ +5\% \ -10\% \ change & \pm 10\% \ change \\ \hline \pm 10\% \ change & \\ \hline \pm 10\% \ change & \\ \hline \pm 10\% \ change & \\ \hline to \ MHz \ 0 \ Within \ 1 \ ppm) & (within \ 1 \ ppm) \\ \hline efference \ output \\ requency & 10 \ MHz \\ \hline requency & 10 \ MHz \\ \hline mplitude & > +4 \ dBm \ into \ 50 \ \Omega \ load \ (typical) \\ \hline xternal \ reference \ input \\ mplitude & > -3 \ dBm \\ \hline to \ WR & 5 \ dBm \ \pm 5 \ dB^4 \\ \hline \end{array}$	Aging rate		< ±3 x10 ⁻⁸ /year or
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Amplitude> -3 dBm Opt UNR $5 \text{ dBm} \pm 5 \text{ dB}^4$	Amplitude	> +4 dBm into 50 Ω load	(typical)
bpt UNR 5 dB^4	External reference input		
F	Amplitude		
nput impedance 50 Ω (nominal)	Opt UNR	5 dBm ±5 dB ⁴	

Useable to 100 kHz
 In ramp sweep mode (Option 007), resolution is limited with narrow spans and slow sweep speeds. Refer to ramp sweep specifications for more information.
 To within 0.1 ppm of final frequency above 250 MHz or within 100 Hz below 250 MHz
 To optimize phase noise 5 dBm ± 2 dB

Digital sweep

Operating modes

Ramp (analog) sweep

(Option 007)¹

			requeries or amplitu	
Sweep range		· · ·		
Frequency sweep		Within instrum	ent frequency range	
Amplitude sweep	Within attenuator hold range			
Dwell time	1 ms to 60 s			
Frequency settling time	28 ms (typical))	
Amplitude settling time		10 ms (typical))	
Number of points		2 to 1601		
Triggering		Auto, external,	single, or GPIB	
Operating modes		Synthesized fre	equency sweep	
		(start/stop), (c	enter/span), (swept	CW)
		Power (amplitu	ude) sweep (start/st	op)
		Manual sweep		
		RPG control be	etween start and sto	p frequencies
		Alternate swee	ер	
				een current and stored states
Sweep span range		Settable from I	minimum ² to full ran	ge
Maximum sweep rate	Start	frequency	Maximum swee	ep rate Max span for
				100ms sweep
	250 kH	Iz to <0.5 GHz	25 MHz/ms	2.5 GHz
0.5 t		<1 GHz	50 MHz/ms	5 GHz
	1 to <		100 MHz/ms	10 GHz
		3.2 GHz	200 MHz/ms	20 GHz
	≥3.2 €		400 MHz/ms	36.8 GHz
Frequency accuracy		\pm 0.05% of span \pm timebase (at 100 ms sweep time, for		
		sweep spans less than maximum values given above)		
				as sweep time increases ³
Sweep time			p, not including band	dswitch and retrace intervals
Resolution		1 ms		
Manual mode			s to 99 seconds	
Auto mode				by maximum sweep rate
		and 8757D set		
Triggering			single, or GPIB	
Markers				ble frequency markers
Display			v or RF amplitude pu	
Functions		M1 to center,	M1/M2 to start/stop	o, marker delta
Two-tone (master/slav	ve)			
measurements ⁴			synchronously track	
			ontrol of start/stop f	
Network analyzer comp	atibility	Fully compatible with Agilent 8757D scalar network analyzer ⁵		
		Also useable with Agilent 8757A/C/E scalar network analyzers		
		for making bas	sic swept measurem	ents. ⁶

Step sweep of frequency or amplitude or both (start to stop) List sweep of frequency or amplitude or both (arbitrary list)

1. During Ramp sweep operation, AM and Pulse Modulation are useable but not specified; FM, Phase

Modulation, Wideband AM and I/Q modulation are not useable.

Minimum settable sweep span is proportional to carrier frequency and sweep time. Actual sweep span may be slightly different than desired setting for spans less than [0.00004% of carrier frequency or 140 Hz] x [sweep time in seconds]. Actual span will always be displayed correctly.

Typical accuracy for sweep times > 100 ms can be calculated from the equation: [(0.005% of span) + (sweep time in seconds)] ± timebase. Accuracy is not specified for sweep times < 100 ms.

^{4.} For Master/Slave operation use Agilent Technologies part #8120-8806 Master/Slave interface cable.

^{5.} When measuring low-pass devices in AC mode, dynamic range may be reduced up to 10dB below 3.2 GHz

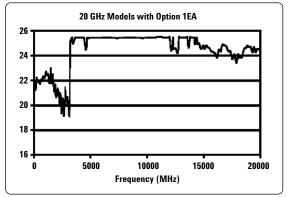
GPIB system interface is not supported with 8757A/C/E, only with 8757D. As a result, some features of 8757A/C/E, such as frequency display, pass-through mode, and alternate sweep, do not function with PSG signal generators.

Output

Power ¹ (dBm)		
Frequency range	Standard	Option 1EA
20 GHz Models		
250 kHz to 3.2 GHz	-20 to +13	-20 to +16
250 kHz to 3.2 GHz (with Option 1E6)	-20 to +13	-20 to +13
> 3.2 to 20 GHz	-20 to +13	-20 to +20
40 GHz Models		
250 kHz to 3.2 GHz	-20 to +9	-20 to +15
250 kHz to 3.2 GHz (with Option 1E6)	-20 to +9	-20 to +12
> 3.2 to 20 GHz	-20 to +9	-20 to +18
> 20 to 40 GHz	-20 to +9	-20 to +14
20 GHz Models with step attenuat	t or (Option 1E1)	
250 kHz to 3.2 GHz	-135 to +11	-135 to +15
250 kHz to 3.2 GHz (with Option 1E6)	-135 to +11	-135 to +12
> 3.2 to 20 GHz	-135 to +11	-135 to +18
40GHz Models with step attenuate	or (Option 1E1)	
250 kHz to 3.2 GHz	-135 to +7	-135 to +14
250 kHz to 3.2 GHz (with Option 1E6)	-135 to +7	-135 to +11
> 3.2 to 20 GHz	-135 to +7	-135 to +16
> 20 to 40 GHz	-135 to +7	-135 to +12
Step attenuator	0 dB and 5 to 115 dB in 10) dB steps

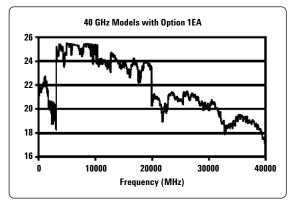
20 GHz Models with Option 1EA

Measured maximum available power



40 GHz Models with Option 1EA

Measured maximum available power



Attenuator hold range	(Same as r	nax power sweep range)		
Minimum	From –20	From -20 dBm to maximum specified output power with		
	step atten	uator in 0 dB position. C	an be offset using	
	Option 1E1	attenuator.		
Amplitude switching spee	d ²			
CW or analog modulation	< 5 ms (ty	pical)		
When using power search	< 25 ms (t	< 25 ms (typical)		
Level accuracy ³ (dB)				
Frequency	> +10 dBm	+10 to –10 dBm	–10 to –20 dBm	
250 kHz to 2 GHz	±0.6	±0.6	±1.4	
2 GHz to 20 GHz	±0.8	±0.8	±1.2	
> 20 to 40 GHz	+1.0	+0.9	+13	

1. Maximum power specification is warranted from 15 to 35° C, and is typical from 0 to 15° C. Maximum power over the 35 to 55° C range typically degrades less than 2 dB.

2. To within 0.1 dB of final amplitude within one attenuator range

 Specifications apply in CW and List/Step sweep modes over the 15 to 35° C temperature range. Degradation outside this range, for power levels > -10 dBm, is typically < 0.3 dB. In Ramp sweep mode (with Option 007), specifications are typical. For instruments with Type-N connectors (Option 1ED), specifications are degraded typically 0.2 dB above 18 GHz.

Level accuracy with step attenuator¹ (dB)

Frequency	> +10 dBm	+10 to –10 dBm	–10 to –70 dBm	–70 to –90 dBm	–90 to –110 dBm
250 kHz to 2 GHz	±0.6	±0.6	±0.7	±0.8	±1.4
> 2 to 20 GHz	±0.8	±0.8	±0.9	±1.0	±1.7
> 20 to 40 GHz	±1.0	±0.9	±1.0	±2.0	

10000

Measured level accuracy +5 dBm Option 1E1

20000

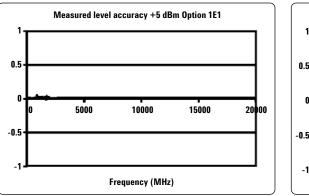
30000

40000

20 GHz level accuracy

40 GHz level accuracy

lo



cy (MHz)	Frequency (MHz)
Resolution	0.01 dB
Temperature stability	0.01 dB/°C (typical)
User flatness correction	
Number of points	2 to 1601 points/table
Number of tables	Up to 10,000, memory limited
Path loss	Arbitrary, within attenuator range
Entry modes	Remote power meter ² , remote bus, manual
(user edit/view)	
Output impedance	50 Ω (nominal)
SWR (internally leveled) (typical)	
250 kHz to 2 GHz	< 1.4:1
> 2 GHz to 20 GHz	< 1.6:1
> 20 GHz to 40 GHz	< 1.8:1
Leveling modes	Internal leveling, external detector leveling, millimeter
	source module, ALC Off
External detector leveling	
Range	-0.2 mV to -0.5 V (nominal) (-36 dBm to +4 dBm using Agilent 33330D/E detector)
Bandwidth	10 kHz (typical) (Note: not intended for pulsed operation)
Maximum reverse power	1/2 Watt (nominal)

^{1.} Specifications apply in CW and List/Step sweep modes over the 15 to 35° C temperature range, with attenuator hold off (normal operating mode). Degradation outside this range, for ALC power levels > -10 dBm, is typically < 0.3 dB. In Ramp sweep mode (with Option 007), specifications are typical. For instruments with type-N connectors (Option 1ED), specifications are degraded typically 0.2 dB above 18 GHz. Level accuracy is not compatible with Agilent Technologies EPM Series (E4418B and E4419B) power meters.

Spectral purity

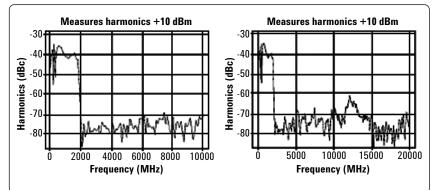
Harmonics¹

< 1 MHz

1 MHz to 2 GHz

> 2 GHz to 20 GHz > 20 GHz to 40 GHz (dBc at +10 dBm or maximum specified output power, whichever is lower) -28 dBc (typical) -28 dBc -55 dBc -50 dBc (typical)





(dBc at +10 dBm or maximum specified output		
power, whichever is lower)		
None		
<-60 dBc		
<-50 dBc		
(dBc at +10 dBm or maxi	mum specified output	
power, whichever is lower	r, for offsets > 3 KHz	
>300 Hz with Option UN	R]) 16	
Spec	Typical	
-65	-72 for > 10 kHz offsets	
-80	-88	
-74	-82	
-68	-76	
-62	-70	
-56	-64	
-50	-58	
Offset from Carrier (dBc/H	łz)	
20 kHz	20 kHz (typical)	
-130	-134	
-136	-140	
-130	-134	
-124	-128	
-120	-124	
-110	-113	
-104	-108	
-98	-102	
	power, whichever is lower None < -60 dBc < -50 dBc (dBc at +10 dBm or maxi power, whichever is lower [>300 Hz with Option UN Spec -65 -80 -74 -68 -62 -56 -50 Offset from Carrier (dBc/H 20 kHz -130 -136 -130 -124 -120 -110 -104	

1. Specifications for harmonics beyond maximum instrument frequencies are typical.

2. Specifications for sub-harmonics beyond maximum instrument frequencies are typical.

 Performance is typical for spurs at frequencies above the maximum operating frequency of the instrument. Specifications apply for CW mode only. Performance typically is –60 dBc between 200 and 250 MHz.

	Option UNR: E Offset from carri	nhanced SSB pha er (dBc/Hz)	se noise (CW)	
Frequency	100 Hz	1 kHz	10 kHz	100 kHz
	spec (typical)	spec (typical)	spec (typical)	spec (typical)
250 kHz to 250 MHz	-94 (-115)	-110 (-123)	-128 (-132)	-130 (-133)
> 250 to 500 MHz	-100 (-110)	-124 (-130)	-132 (-136)	-136 (-141)
> 500 MHz to 1 GHz	-94 (-104)	-118 (-126)	-130 (-135)	-130 (-135)
> 1 to 2 GHz	-88 (-98)	-112 (-120)	-124 (-129)	-124 (-129)
> 2 to 3.2 GHz	-84 (-94)	-108 (-116)	-120 (-125)	-120 (-125)
> 3.2 to 10 GHz	-74 (-84)	-98 (-106)	-110 (-115)	-110 (-115)
> 10 to 20 GHz	-68 (-78)	-92 (-100)	-104 (-107)	-104 (-109)
> 20 to 40 GHz	-62 (-72)	-86 (-94)	-98 (-101)	-98 (-103)
Residual FM				
CW mode		< N x 6 Hz (typic	cal)	
Option UNR		< N x 4 Hz (typic	cal)	
Ramp sweep mode:	Ramp sweep mode: < N x 1 kHz (typical)			
(rms, 50 Hz to 15 kHz bandwidth)				
Broadband noise (CW mode at +10 dBm output, for offsets > 10 MHz)				
> 2.4 to 20 GHz <-148 dBc/Hz (typical)				
> 20 to 40 GHz		<-141 dBc/Hz (typical)		

Measured phase noise

10M

100M



-40

-50

-60

-70

-80

-90

-100

-110 -120

-130

-140

-150

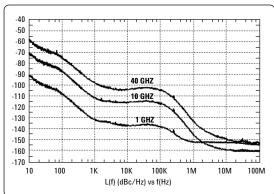
-160

-170

10

100





Measured Standard vs. Option UNR at 10 GHz

1K

10K

L(f) (dBc/Hz) vs f(Hz)

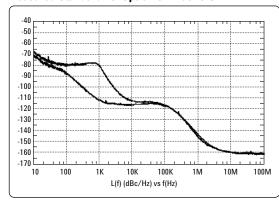
40 GHZ

10 GHZ

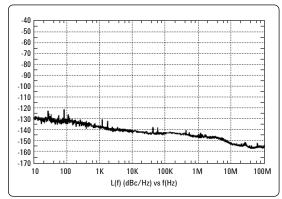
1 GHZ

100K

1M







Standard				
Carrier	SONET/SDH	RMS jitter	Unit intervals	Time
frequency	data rates	bandwidth	(µUI)	(fs)
155 MHz	155 MB/s	100 Hz to 1.5 MHz	48	303
622 MHz	622 MB/s	1 kHz to 5 MHz	34	50
2.488 GHz	2488 MB/s	5 kHz to 15 MHz	65	25
9.953 GHz	9953 MB/s	20 kHz to 80 MHz	173	16
Option UNR				
Carrier	SONET/SDH	RMS jitter	Unit intervals	Time
frequency	data rates	bandwidth	(µUI)	(fs)
155 MHz	155 MB/s	100 Hz to 1.5 MHz	47	297
622 MHz	622 MB/s	1 kHz to 5 MHz	26	40
2.488 GHz	2488 MB/s	5 kHz to 15 MHz	66	25
9.953 GHz	9953 MB/s	20 kHz to 80 MHz	161	15
Maximum devi		N x 8 MHz		
Resolution	ation		or 1 Hz, whichever i	a graatar
	r00V		deviation + 20 Hz	s greater
Deviation accu	racy		tions $< N \times 800$ kHz)	
Modulation fre	quency response	(T KHZ TALE, UEVIA	$\frac{1000}{10} \times 10 \times 000 \text{ km/s}$	
Path		Rates (at 100 k	Hz deviation)	
		1 dB Bandwidt	h 3 dB Bandwi	dth (typical)
FM 1		dc/20 Hz to 100	kHz dc/5 Hz to 10 I	MHz
-M 2		dc/20 Hz to 100	kHz dc/5 Hz to 1 M	lHz
dc FM ² carrier	offset	$\pm 0.1\%$ of set deviation + (N x 8 Hz)		
Distortion		< 1% (1 kHz rate, deviations < N x 800 kHz)		
Sensitivity		±1 V _{peak} for indicated deviation		
Paths		FM1 and FM2 ar	e summed internally	for composite
		modulation. Either path may be switched to any one of		
		the modulation so	ources: Ext1, Ext2, int	ernal1, internal2
		The FM2 path is	limited to a maximum	rate of 1 MHz.
		T I F1 I 0		

Phase modulation

Frequency modulation

Maximum deviation	N x 80 radians (N x 8 radians in high-bandwidth mode)		
Resolution	0.1% of set deviation		
Deviation accuracy	$< \pm 5\%$ of deviation + 0.01 radians		
	(1 kHz rate, normal BW mo	ode)	
Modulation frequency response			
Mode	Maximum deviation	Rates (3 dB BW)	
Normal BW	N x 80 rad	dc to 100 kHz	
High BW	N x 8 rad	dc to 1 MHz (typical)	
Distortion	< 1 % (1 kHz rate, THD, dev < N x 80 rad, normal BW mode		
Sensitivity	±1 V _{neak} for indicated deviation		
Paths	Φ M1 and Φ M2 are summed internally for composite		
	modulation. Either path ma	ay be switched to any one of	
		t1, Ext2, internal1, internal2.	
	The Φ M2 path must be set	to a deviation less than Φ M1	
	1		

The FM2 path must be set to a deviation less than FM1.

 Calculated from phase noise performance in CW mode only at +0 dBm. For other frequencies, data rate, or bandwidths, please contact your sales representative.

2. At the calibrated deviation and carrier frequency, within 5°C of ambient temperature at time of user calibration.

Amplitude modulation	Depth	Linear mod	le	Exponential (log) mode
(f _c > 2 MHz) ¹ (typical)				(Downward modulation only)
	Maximum	> 90%		> 20 dB
	Settable ²	0 to 100 %		0 to 40 dB
	Resolution	0.1%		0.01 dB
	Accuracy	< ±(6 % of :	setting + 1 %)	$< \pm (2\% \text{ of setting} + 0.2 \text{ dB})$
	(1 kHz rate)			
	Ext sensitivity	±1 V _{peak} for		-1 V for indicated depth
		indicated de		
	Rates (3 dB bandwidth, 30% depth) dc/10 Hz to 100 kHz (typical) (useable to 1 MHz)			
	Distortion (1 kHz rate, lin	iear mode, THD)		
	30% AM		< 1.5%	
	90% AM		< 4 %	
	modulation. Eit		are summed internally for composite her path may be switched to any one of sources: Ext1, Ext2, internal1, internal2.	
External modulation inputs	Modulation types		AM, FM, and o	
(Ext1 & Ext2)	Input impedance		50 or 600 Ω (r	nominal) switched
	High/low indicator (100 Hz to 10 MHz BW, ac coupled inputs only) Activated when 3% (nominal)		n input level error exceeds	
	internal1, or internal2) Any	y given source (Ex		nputs from any two sources (Ext1, Ext2, 1, or internal2) may be routed
Internal modulation source	internal1, or internal2) Any to only one activated mode	y given source (Ex ulation type.	tt1, Ext2, internal	1, or internal2) may be routed
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p	y given source (Ex ulation type.	tt1, Ext2, internal	
Internal modulation source	internal1, or internal2) Any to only one activated mode	y given source (Ex ulation type.	tt1, Ext2, internal bendent signals (i Sine, square, p	1, or internal2) may be routed
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, Φ M, or LF Out.	y given source (Ex ulation type.	tt1, Ext2, internal bendent signals (i Sine, square, p	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle,
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, Φ M, or LF Out. Waveforms	y given source (Ex ulation type.	tt1, Ext2, internal bendent signals (i Sine, square, p	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range	y given source (Ex ulation type.	tt1, Ext2, internal bendent signals (i Sine, square, p Gaussian noise	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine	y given source (Ex ulation type.	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle	y given source (Ex ulation type.	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution	y given source (Ex ulation type.	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy	y given source (Ex ulation type.	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out	y given source (Ex ulation type.	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz ase ernal2. Also provides monitoring of
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude Output impedance	y given source (Ex ulation type.	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz (Hz ase ernal2. Also provides monitoring of ernal2 when used for AM, FM, or ΦM. ominal) into 50 Ω
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude	y given source (Ex ulation type.	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int 0 to 3 V _{peak} , (n	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz (Hz ase ernal2. Also provides monitoring of ernal2 when used for AM, FM, or ΦM. ominal) into 50 Ω
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude Output impedance	y given source (Ex ulation type. provides two indep	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int 0 to 3 V _{peak} , (n	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz (Hz ase ernal2. Also provides monitoring of ernal2 when used for AM, FM, or ΦM. ominal) into 50 Ω
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude Output impedance Swept sine mode:	y given source (Ex ulation type. provides two indep	tt1, Ext2, internal bendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int 0 to 3 V _{peak} , (n 50 W (nominal	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz (Hz ase ernal2. Also provides monitoring of ernal2 when used for AM, FM, or ΦM. ominal) into 50 Ω
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude Output impedance Swept sine mode: (frequency, phase continue	y given source (Ex ulation type. provides two indep	tt1, Ext2, internal bendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int 0 to 3 V _{peak} , (n 50 W (nominal	1, or internal2) may be routed internal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz ase ernal2. Also provides monitoring of ernal2 when used for AM, FM, or Φ M. ominal) into 50 Ω)
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude Output impedance Svept sine mode: (frequency, phase continue Operating modes	y given source (Ex ulation type. provides two indep	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int 0 to 3 V _{peak} , (n 50 W (nominal Triggered or co 1 Hz to 1 MHz	1, or internal2) may be routed internal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz ase ernal2. Also provides monitoring of ernal2 when used for AM, FM, or Φ M. ominal) into 50 Ω)
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude Output impedance Svept sine mode: (frequency, phase continue Operating modes Frequency range	y given source (Ex ulation type. provides two indep	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int internal1 or int 0 to 3 V _{peak} , (n 50 W (nominal Triggered or co 1 Hz to 1 MHz	1, or internal2) may be routed nternal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz Hz ase ernal2. Also provides monitoring of ernal2 when used for AM, FM, or Φ M. ominal) into 50 Ω) ntinuous sweeps KHz sweeps/s, equivalent to sweep
Internal modulation source	internal1, or internal2) Any to only one activated mode Dual function generators p AM, FM, ΦM, or LF Out. Waveforms Rate range Sine Square, ramp, triangle Resolution Accuracy LF out Output Amplitude Output impedance Svept sine mode: (frequency, phase continue Operating modes Frequency range	y given source (Ex ulation type. provides two indep	tt1, Ext2, internal pendent signals (i Sine, square, p Gaussian noise 0.5 Hz to 1 MH 0.5 Hz to 100 H 0.5 Hz Same as timeb Internal1 or int 0 to 3 V _{peak} , (n 50 W (nominal Triggered or co 1 Hz to 1 MHz 0.5 Hz to 100 H	1, or internal2) may be routed Internal1 and internal2) for use with ositive ramp, negative ramp, triangle, , uniform noise, swept sine, dual sine ²¹ Iz Hz Hz ernal2. Also provides monitoring of ernal2 when used for AM, FM, or Φ M. ominal) into 50 Ω) ntinuous sweeps (Hz sweeps/s, equivalent to sweep 2 s

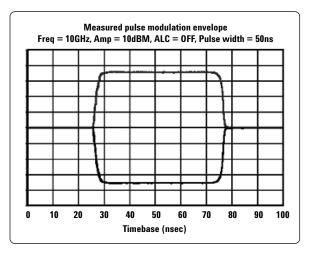
 For f_c < 2 MHz AM is usable but not specified. AM specifications apply with ALC on, and envelope peaks < maximum specified power. For instruments without Option 1E1 attenuator, specs apply for carrier amplitude > -2 dBm.

2. For AM depth settings > 90% or > 20 dB, deep AM mode or 1 kHz ALC BW is recommended.

3. Internal2 is not available when using swept sine or dual sine modes.

Pulse modulation¹

	Standard ≥ 500 MHz to ≤ 3.2 GHz	Option 1E6 ≥ 10 MHz to ≤ 3.2 GHz	> 3.2 GHz
On/off ratio	80 dB (typical)	80 dB	80 dB
Rise/fall times (Tr, Tf)	100 ns (typical)	10 ns (8 ns typical)	10 ns (6 ns typical)
Pulse width			
Internally leveled	≥ 2 µs (typical)	≥ 1µs	≥ 1µs
Level hold	≥ 0.5 µs (typical)	\geq 20 ns (typical)	≥ 20 ns (typical)
(ALC Off with power search	1) ²		
Repetition frequency			
Internally leveled	10 Hz to 250 kHz (typical)	10 Hz to 500 kHz (typical)	10 Hz to 500 kHz (typical)
Level hold	dc to 1 MHz (typical)	dc to 10 MHz (typical)	dc to 10 MHz (typical)
(ALC Off with power search	n) ²		
Level accuracy	·		
(relative to CW)			
Internally leveled	±0.5 dB	±0.5 dB	±0.5 dB
			±0.15 (typical)
Level hold	±0.5 dB (typical)	±1.0 dB (typical)	\leq 20 GHz ±0.8 dB
			(typical)
(ALC Off with power search	ר) ²		\leq 40 GHz ±1.2 dB
			(typical)
Width compression	±50 ns (typical)	±5 ns (typical)	±5 ns (typical)
Video feed-through ³	< 200 mV (typical)	< 125 mV (typical)	< 2 mV (typical)
Video delay			
(Ext input to Video)	40 ns (nominal)	40 ns (nominal)	40 ns (nominal)
RF delay (Tm)			
(Video to RF output)	280 ns (nominal)	45 ns (nominal)	35 ns (nominal)
Pulse overshoot (Vor)	< 10% (typical)	< 1GHz 20% (typical) ≥ 1GHz 10% (typical)	< 10% (typical)
Input level	+1 V _{peak} = RF On	+1 V _{peak} = RF On	+1 V _{peak} = RF On
Input impedance	50 $\dot{\mathbf{\Omega}}$ (nominal)	50 $\hat{\mathbf{\Omega}}$ (nominal)	50 Ω (nominal)



With ALC off, specs apply after the execution of power search. For instruments without a step attenuator, specs apply between 0 and +10 dBm. For instruments with the step attenuator, specs apply with Atten Hold Off, or ALC level between 0 and +10 dBm.

^{2.} Power search is a calibration routine that improves level accuracy in ALC-off mode. Un-pulsed RF power will be present typically up to 50 ms when executing power search.

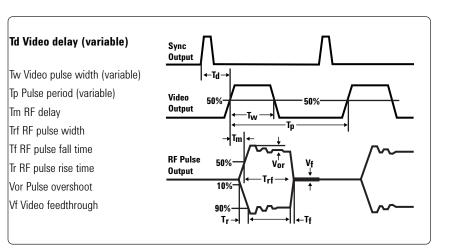
^{3.} With attenuator in 0 dB position. Video feed-through decreases with attenuator setting.

Internal pulse generator

Modes	Free-run, triggered, triggered with delay, doublet, and
	gated. Triggered with delay, doublet, and gated require
	external trigger source.
Period (PRI) (Tp)	70 ns to 42 s
	(Repetition frequency: 0.024 Hz to 14.28 MHz)
Pulse width (Tw)	10 ns to 42 s
Delay (Td)	
Free-run mode	0 to ±42 s
Triggered with delay and doublet modes	75 ns to 42s with ± 10 ns jitter

Resolution

10 ns (width, delay, and PRI)



Remote programming	Interfaces	GPIB (IEEE-488.2,1987) with listen and talk, RS-232, and 100aar LAN interface
	Control languages	and 10BaseT LAN interface. SCPI version 1997.0. Also will emulate most applicable
	Control languages	Agilent 836xxB, Agilent 837xxB, and Agilent 8340/41B
		commands, providing general compatibility with ATE
		systems which include these signal generators.
	IEEE-488 functions	SH1, AH1, T6, TE0, L4, LE0, SR1, RL1, PP0, DC1,
		DT0, C0, E2.
	ISO compliant	This family of signal generators is manufactured in an
	·	ISO-9001 registered facility in concurrence with Agilent
		Technologies commitment to quality.
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General	Power requirements	90 to 132 Vac 50 to 60 Hz, or 195 to 267
		Vac 50 to 60 or 400 Hz, (automatically selected),
		300 W maximum.
	Operating temperature range	0 to 55 °C
	Storage temperature range ¹	-40 to 71 °C
	Shock and vibration	Meets MIL-STD-28800E Type III, Class 3.
	EMC	Conducted and radiated interference and immunity
		meets IEC/EN 61326-1 and MIL-STD-461C Part 2, RE02.
		Meets radiated emission requirements of CISPR Pub
		11/1997 Group 1 class A.
	Storage registers	Memory is shared by instrument states, user data files,
		sweep list files, and waveform sequences. Depending
		on the number and size of these files, up to 800 storage
		registers and 10 register sequences are available.
	Security	Display blanking.
	Compatibility	Agilent Technologies 83550 Series millimeter heads,
		Agilent Technologies 8757D Scalar Network Analyzers,
		Agilent Technologies EPM Series Power Meters.
	Self-test	Internal diagnostic routine tests most modules
		(including microcircuits) in a preset condition. For each
		module, if its node voltages are within acceptable limits,
		then the module "passes" the test.
	Weight	< 22 kg (48 lb.) net, < 30 kg (68 lb.) shipping.
	Dimensions	178 mm H x 426 mm W x 498 mm D
		(7" H x 16.8" W x 19.6" D in.).
	Recommended calibration cycle	24 months

1. Storage below –20°C Instrument states may be lost.

Front panel connectors

Rear panel connectors (All connectors are BNC female unless otherwise noted.)¹

(All connectors are BNC female unless otherwise noted.)¹

RF output For 20 GHz models For 40 GHz models	Nominal output impedance 50 Ω . Precision APC-3.5 male, or Type-N with Option 1ED. Precision 2.4 mm male; plus 2.4 - 2.4 mm and 2.4 - 2.9 mm female adaptors also included.
ALC input	Used for negative external detector leveling. Nominal input impedance 120 k Ω , damage level ±15 V.
LF output (E8257C only)	Outputs the internally generated LF source. Nominal output impedance 50 Ω .
External input 1 (E8257C only)	Drives either AM, FM, or Φ M. Nominal input impedance 50 or 600 Ω , damage levels are 5 V _{rms} and 10 V _{peak} .
External input 2 (E8257C only)	Drives either AM, FM, or Φ M. Nominal input impedance 50 or 600 Ω , damage levels are 5 V _{rms} and 10 V _{peak} .
Pulse/trigger gate input (E8257C only)	Accepts input signal for external fast pulse modulation. Also accepts external trigger pulse input for internal pulse modulation. Nominal impedance 50 Ω . Damage levels are 5 V _{rms} and 10 V _{peak} .
Pulse video out (E8257C only)	Outputs a signal that follows the RF output in all pulse modes. TTL-level compatible, nominal source impedance 50 Ω .
Pulse sync out (E8257C only)	Outputs a synchronizing pulse, nominally 50 ns width, during internal and triggered pulse modulation. TTL-level compatible, nominal source impedance 50 Ω .
Auxiliary interface (Dual mode)	Used for RS-232 serial communication and for Master/Slave source synchronization. (9-pin subminiature female connector).
GPIB	Allows communication with compatible devices.
LAN	Allows 10BaseT LAN communication
10 MHz input	Accepts an external reference (timebase) input (at 1, 2, 2.5, 5, 10 MHz for standard and 10 MHz only for Option UNR) Nominal input impedance 50 Ω . Damage levels > +10 dBm
10 MHz output	Outputs internal or external reference signal. Nominal output impedance 50 Ω . Nominal output power +8 dBm
Sweep output (Dual mode)	Supplies a voltage proportional to the RF power or frequency sweep ranging form 0 volts at the start of sweep to +10 volts (nominal) at the end of sweep, regardless of sweep width.
	When connected to an Agilent 8757D Scalar Network Analyzer (Option 007), generates a selectable number of equally spaced 1 us pulses (nominal) across a ramp (analog) sweep. Number of pulses can be set form 101 to 1601 by remote control from the 8757D.

Digital inputs and output are 3.3 V CMOS unless indicated otherwise. Inputs will accept 5 V CMOS, 3V CMOS, or TTL voltage levels.

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Stop sweep In/Out	Open-collector, TTL-compatible input/output. In ramp sweep operation, provides low level (nominally 0 V) during sweep retrace and bandcross intervals, and high level during the forward portion of the sweep. Sweep will stop when grounded externally, sweep will resume when allowed to go high.
Trigger output (Dual mode)	Outputs a TTL signal. High at start of dwell, or when waiting for point trigger; low when dwell is over or point trigger is received, In ramp sweep mode, provides 1601 equally-spaced 1us pulses (nominal) across a ramp sweep. When using LF Out, provides 2 us pulse at start of LF sweep.
Trigger input	Accepts ΠL signal for triggering point-to-point in manual sweep mode, or to trigger start of LF sweep. Damage levels $\geq +10$ V or ≤ -4 V.
Source module interface	Provides bias, flatness correction, and leveling connections to the Agilent model 83550 Series mm-wave source modules.
Source settled	Provides an output trigger that indicates when the signal generator has settled to a new frequency or power level. High indicates source not settled, Low indicates source settled.
Z-axis Blank/Markers	During Ramp Sweep, supplies + 5 V (nominal) level during retrace and bandswitch intervals. Supplies – 5V (nominal) level when the RF frequency is at a marker frequency.
EFC	$>$ 0.25 ppm for –5 to +5 V. Input impedance: >1 M Ω

Related Agilent literature	<i>PSG Signal Generator</i> , Brochure Literature number 5988-7538EN
	<i>Agilent E8247/57C PSG CW and Analog Signal Generators</i> Data Sheet Literature number 5988-7454EN
	<i>Agilent E8267C PSG Vector Signal Generato</i> r Data Sheet Literature number 5988-6632EN
	<i>PSG Self Guided Demo</i> Literature number 5988-2414EN
	<i>PSG Configuration Guide</i> Literature number 5988-7541EN
	<i>PSG Series Product Note: Millimeter Head</i> Literature number 5988-2567EN
	<i>PSG Two-tone and Multitone Application Note AN 1410</i> Literature number 5988-7689EN

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